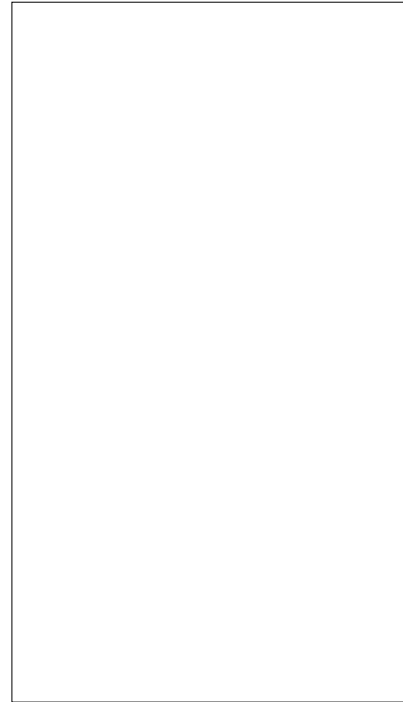


JCT816C 16A SCR

Rev.A.1.1

DESCRIPTION:

With high ability to withstand the shock loading of large current, JCT816C of silicon controlled rectifiers provides high dV/dt rate with strong resistance to electromagnetic interference. It is especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc. Package TO-220C is RoHS compliant.



MAIN FEATURES

ABSOLUTE MAXIMUM RATINGS

P3 (a) 10 (e) 10 (O) TJ 0 TJ 5 (m) TJ (i) 6 (n) 1a (f) -8.1) 10 (net) 2 p) 2.5a (n) se

Average gate power dissipation ($T_j=125^\circ\text{C}$)	$P_{G(AV)}$	1	W
Peak gate power	P_{GM}	20	W
Peak pulse voltage ($T_j=25^\circ\text{C}$; non-repetitive, off-state; FIG.7)	V_{pp}	0.5	kV

ELECTRICAL CHARACTERISTICS

ORDERING INFORMATION

<u>J</u>	<u>CT</u>	<u>8</u>	<u>16</u>	<u>C</u>
JieJie Microelectronics Co., Ltd.	SCRs	8:V _{DRM} /V _{RRM} 1800 V	I _{T(RMS)} :16A	C:TO-220C

MARKING

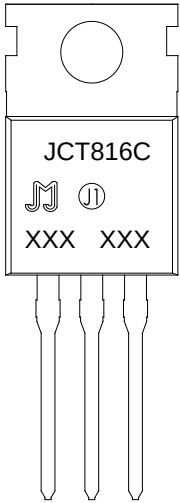
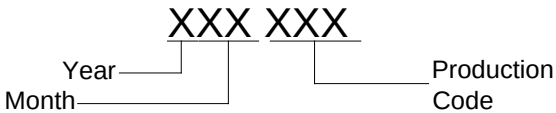
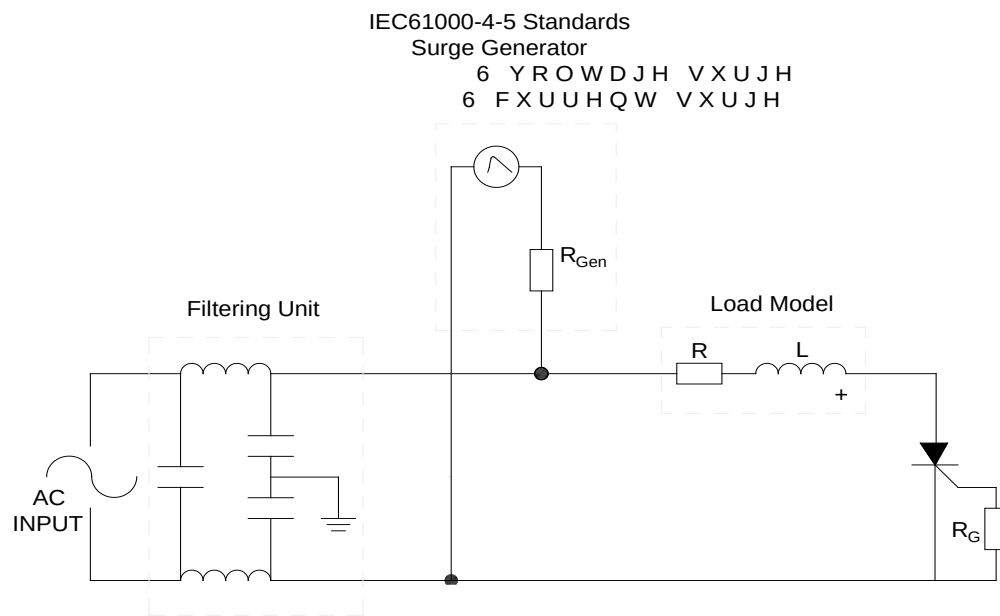
	
---	--

FIG.7 ÖTest circuit for inductive and resistive loads to IEC-61000-4-5 standards.



ORDERING INFORMATION

Order code	Voltage $V_{\text{DRM}}/V_{\text{RRM}}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
JCT816C	800	15	TO-220C	50	Tube

Document Revision History

Date	Revision	Changes
Apr.13, 2023	A.1.0	Last update

PACKAGE MECHANICAL DATA



